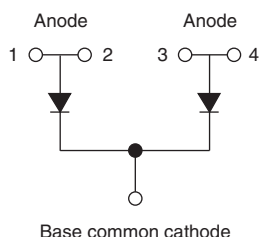


Not Insulated SOT-227 Power Module U-Series FRED Pt® Gen 4, 600 V



SOT-227



FEATURES

- Gen 4 FRED Pt® dices technology
- Ultrasoft reverse recovery characteristics
- Low I_{RRM} and reverse recovery charge
- Very low forward voltage drop
- Not insulated package
- 175 °C operating junction temperature
- Optimized for power conversion: welding and industrial SMPS applications
- Plug-in compatible with other SOT-227 packages
- Easy to assemble
- Direct mounting to heatsink
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

DESCRIPTION

Gen 4 FRED technology, state of the art, ultra low V_F , soft switching optimized for IGBT F/W diode.

The minimized conduction loss, optimized storage charge and low recovery current minimized the switching losses and reduce the over dissipation in the switching element and snubbers.

PRIMARY CHARACTERISTICS

V_R	600 V
$I_{F(AV)}$ at $T_C = 124\text{ °C}$ per module ⁽¹⁾	450 A
t_{rr}	97 ns
Type	Modules - Diode FRED Pt®
Package	SOT-227
Circuit configuration	Common cathode

Note

⁽¹⁾ All 4 anode terminals connected

ABSOLUTE MAXIMUM RATINGS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current per diode	I_F	$T_C = 133\text{ °C}$	250	A
Single pulse forward current per diode	I_{FSM}	$T_C = 25\text{ °C}$, 10 ms sine or 6 ms rectangular pulse	1170	
Maximum power dissipation per module	P_D	$T_C = 135\text{ °C}$	727	W
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C

**ELECTRICAL SPECIFICATIONS PER DIODE** ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 500\text{ }\mu\text{A}$	600	-	-	V
Forward voltage, per leg	V_{FM}	$I_F = 100\text{ A}$	-	1.18	1.32	
		$I_F = 100\text{ A}, T_J = 125\text{ }^{\circ}\text{C}$	-	1.00	-	
		$I_F = 100\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	-	0.91	-	
		$I_F = 200\text{ A}$	-	1.34	1.60	
		$I_F = 200\text{ A}, T_J = 125\text{ }^{\circ}\text{C}$	-	1.19	-	
		$I_F = 200\text{ A}, T_J = 175\text{ }^{\circ}\text{C}$	-	1.11	-	
Reverse leakage current, per leg	I_{RM}	$V_R = V_R = 600\text{ V}$	-	0.2	150	μA
		$V_R = V_R = 600\text{ V}, T_J = 125\text{ }^{\circ}\text{C}$	-	169	-	mA
		$V_R = V_R = 600\text{ V}, T_J = 175\text{ }^{\circ}\text{C}$	-	2.1	-	
Junction capacitance, per leg	C_T	$V_R = 600\text{ V}, f = 1\text{ MHz}$	-	173	-	pF

DYNAMIC RECOVERY CHARACTERISTICS PER DIODE ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time, per leg	t_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	97	-	ns
		$T_J = 125\text{ }^{\circ}\text{C}$	-	164	-	
Peak recovery current, per leg	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	16	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	33	-	
Reverse recovery charge, per leg	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	794	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	2736	-	

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction to case, single leg conducting	R_{thJC}		-	-	0.11	$^{\circ}\text{C/W}$
Junction to case, both leg conducting			-	-	0.055	
Case to heatsink, per module	R_{thCS}	Flat, greased surface	-	0.1	-	
Weight			-	30	-	g
Mounting torque		Torque to terminal	-	-	1.1 (9.7)	Nm (lbf. in)
		Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf. in)
Case style			SOT-227			

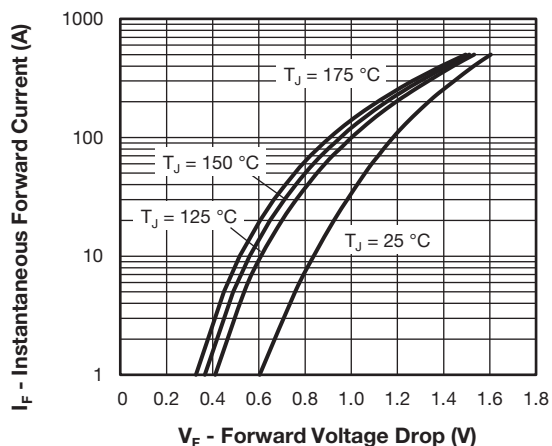


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Diode)

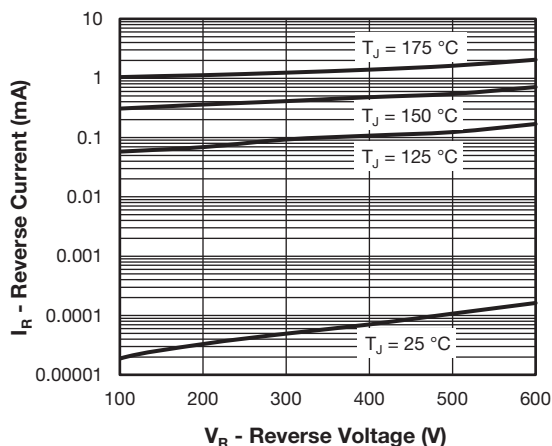


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Diode)

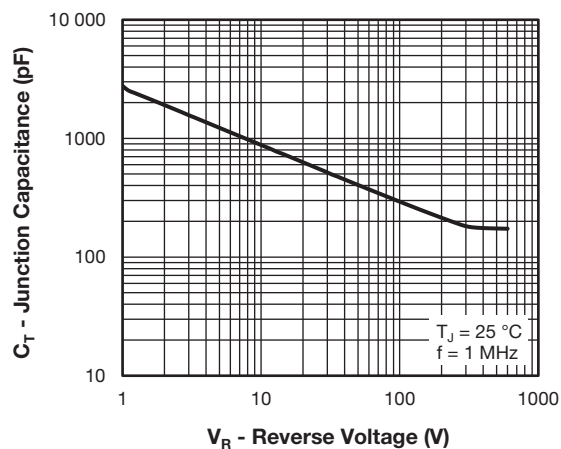


Fig. 3 - Typical Junction Capacitance vs Reverse Voltage (Per Diode)

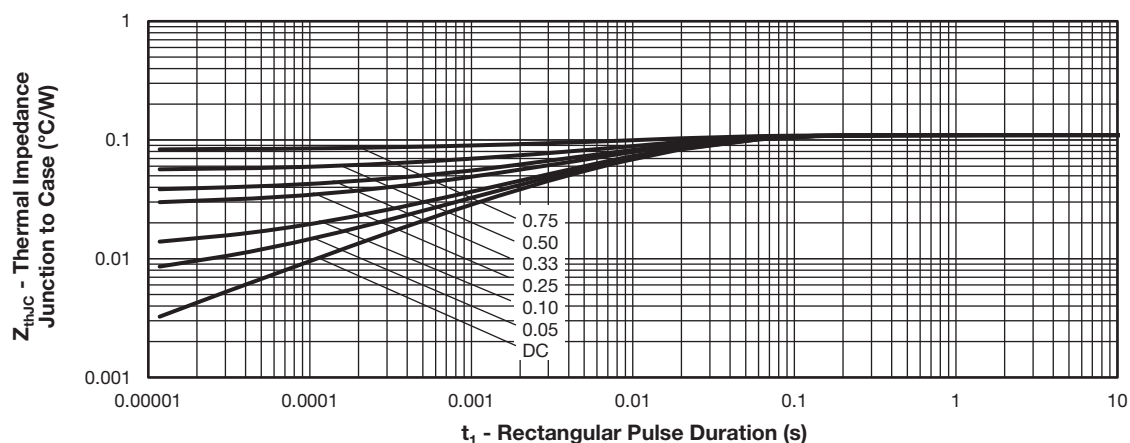


Fig. 4 - Maximum Thermal Impedance Junction-to-Case Characteristics (Per Diode)

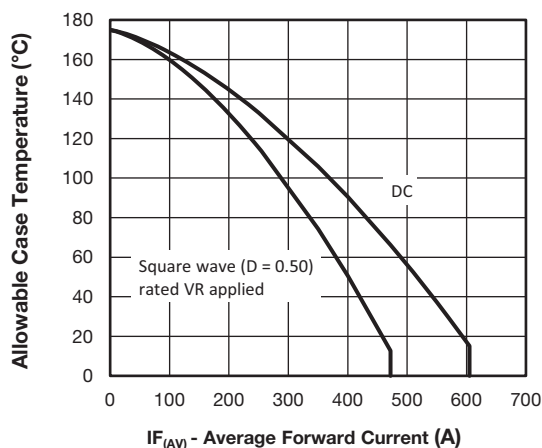


Fig. 5 - Maximum Current Rating Capability (Per Diode)

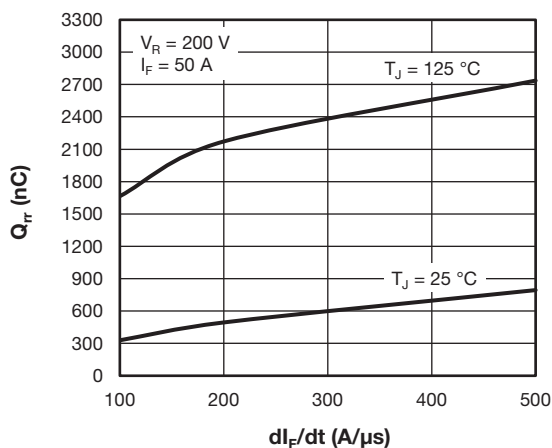


Fig. 7 - Typical Reverse Recovery Charge vs. dI_F/dt (Per Diode)

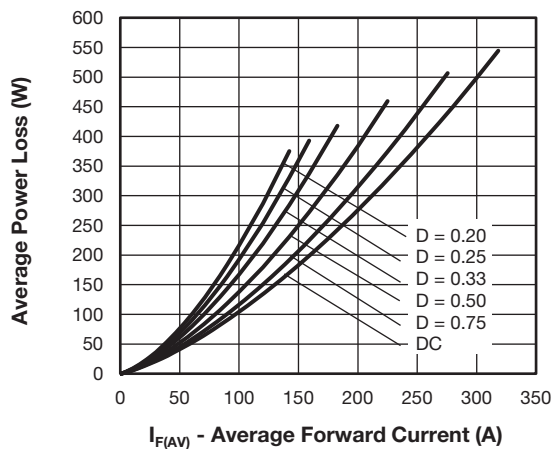


Fig. 6 - Forward Power Loss Characteristics (Per Diode)

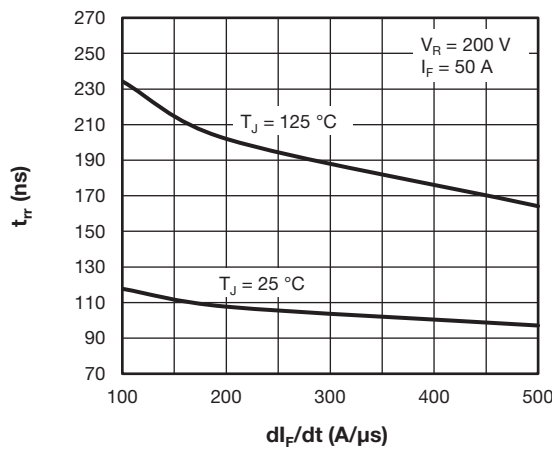


Fig. 8 - Typical Reverse Recovery Time vs. dI_F/dt (Per Diode)

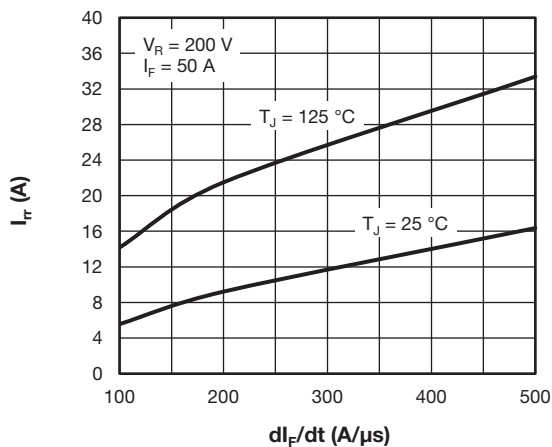
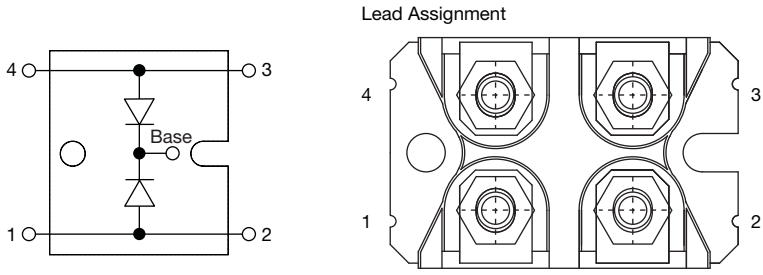


Fig. 9 - Typical Reverse Recovery Current vs. dI_F/dt (Per Diode)

ORDERING INFORMATION TABLE

Device code	VS-	UF	L	450	C	B	60
	1	2	3	4	5	6	7
1	- Vishay Semiconductors product						
2	- Ultrafast rectifier						
3	- Ultrafast Pt diffused, low V_F						
4	- Current rating (450 = 450 A)						
5	- Circuit configuration (2 common cathode diodes)						
6	- Package indicator (SOT-227 standard not insulated)						
7	- Voltage rating (60 = 600 V)						

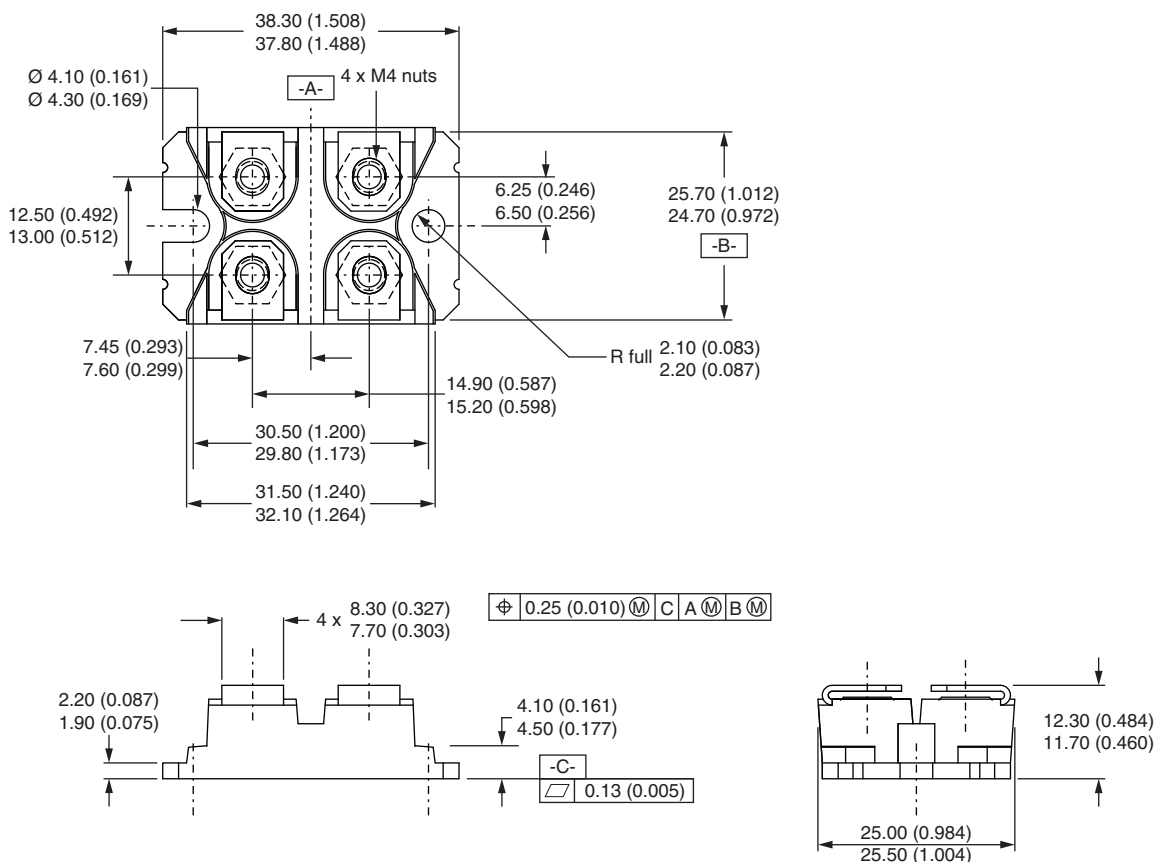
Quantity per tube is 10 pcs, M4 screw and washer included

CIRCUIT CONFIGURATION		
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING
Common cathode	C	

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95423
Part marking information	www.vishay.com/doc?95425

SOT-227 Generation II

DIMENSIONS in millimeters (inches)



Note

- Controlling dimension: millimeter



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